

Ultrafast Rectifier, 3 A FRED Pt®



Cathode O Anode

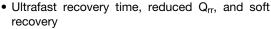
DESIGN SUPPORT TOOLS

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PRIMARY CHARACTERISTICS				
I _{F(AV)}	3 A			
V_{R}	600 V			
V _F at I _F	0.99 V			
t _{rr}	50 ns			
T _J max.	175 °C			
Package	SlimSMA (DO-221AC)			
Circuit configuration	Single			

FEATURES





• 175 °C maximum operating junction temperature

Low forward voltage drop

Low leakage current

ROHS COMPLIANT HALOGEN

FREE

 Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time, and fast recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in snubber, output operation, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V_{RRM}		600	V	
Average rectified forward current	I _{F(AV)}	T _C = 117 °C ⁽¹⁾	3	۸	
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	43	A	
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C	

Note

⁽¹⁾ Device on PCB with 8 mm x 16 mm soldering lands

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS MIN. TYP. M		MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
Forward voltage V _F	\/	I _F = 3 A	-	1.15	1.35	V
	V _F	I _F = 3 A, T _J = 150 °C	-	0.99	1.2	
Reverse leakage current		$V_R = V_R$ rated	-	-	3	
	IR	T _J = 150 °C, V _R = V _R rated	-	-	100	μA
Junction capacitance	C _T	V _R = 600 V	-	6.2	-	pF



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	45	-	
Reverse recovery time t _{rr}	+	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		-	-	50	ns
	T _J = 25 °C		-	52	-		
		T _J = 125 °C		-	82	-	
Peak recovery current I _{RRM}	T _J = 25 °C	$I_F = 3 A$ $dI_F/dt = 500 A/\mu s$ $V_R = 400 V$	-	7.3	-	A	
	T _J = 125 °C		-	10	-		
Reverse recovery charge Q _{rr}	0	T _J = 25 °C		-	210	-	
	T _J = 125 °C		-	400	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS MIN		TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to lead	R _{thJL}	Device mounted on PCB with 8 mm x 16 mm soldering lands	-	16	-	°C/W
Thermal resistance, junction to ambient	R _{thJA}	Device mounted on PCB with 3 mm x 3 mm soldering lands	-	115	-	C/VV
Approximate Weight				0.032		g
Approximate Weight				0.0011		oz.
Marking device		Case style SlimSMA (DO-221AC)		31	J6	

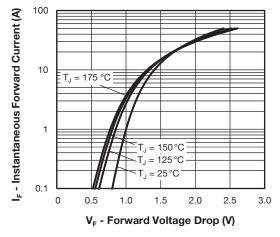


Fig. 1 - Typical Forward Voltage Drop Characteristics

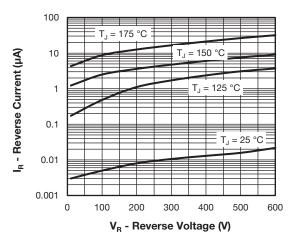


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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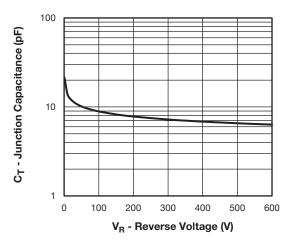


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

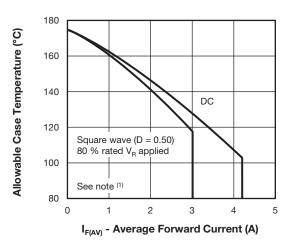


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

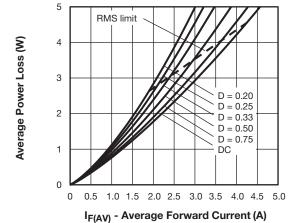
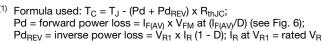


Fig. 5 - Forward Power Loss Characteristics

Note



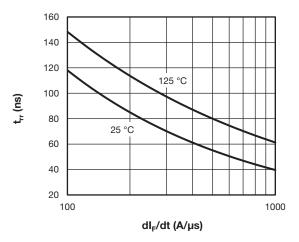


Fig. 6 - Typical Reverse Recovery vs. dl_F/dt

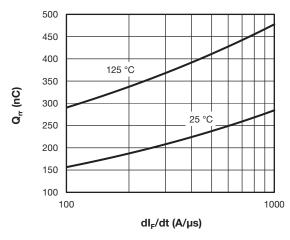


Fig. 7 - Typical Stored Charge vs. dl_F/dt

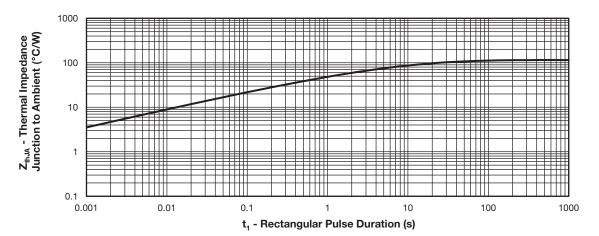
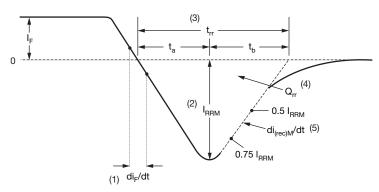


Fig. 8 - Thermal Impedance Z_{thJA}



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} x I_{RRM}}{2}$$

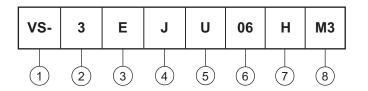
(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (3 = 3 A)

3 - Circuit configuration:

E = single diode

4 - J = SlimSMA package

5 - Process type,

U = ultrafast recovery

- Voltage code (06 = 600 V)

7 - H = AEC-Q101 qualified

8 - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

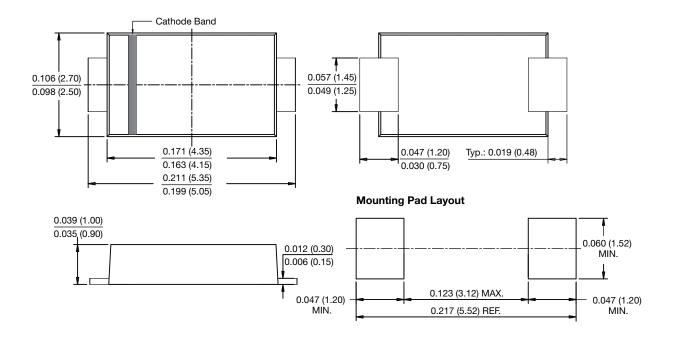
ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-3EJU06HM3/6A	3500	3500	7" diameter plastic tape and reel		
VS-3EJU06HM3/6B	14 000	14 000	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95571			
Part marking information	www.vishay.com/doc?95562			
Packaging information	www.vishay.com/doc?88869			



DO-221AC (SlimSMA)

DIMENSIONS in inches (millimeters)





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